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Applications of "<u>Embedded -</u> <u>Microcontrollers</u>"

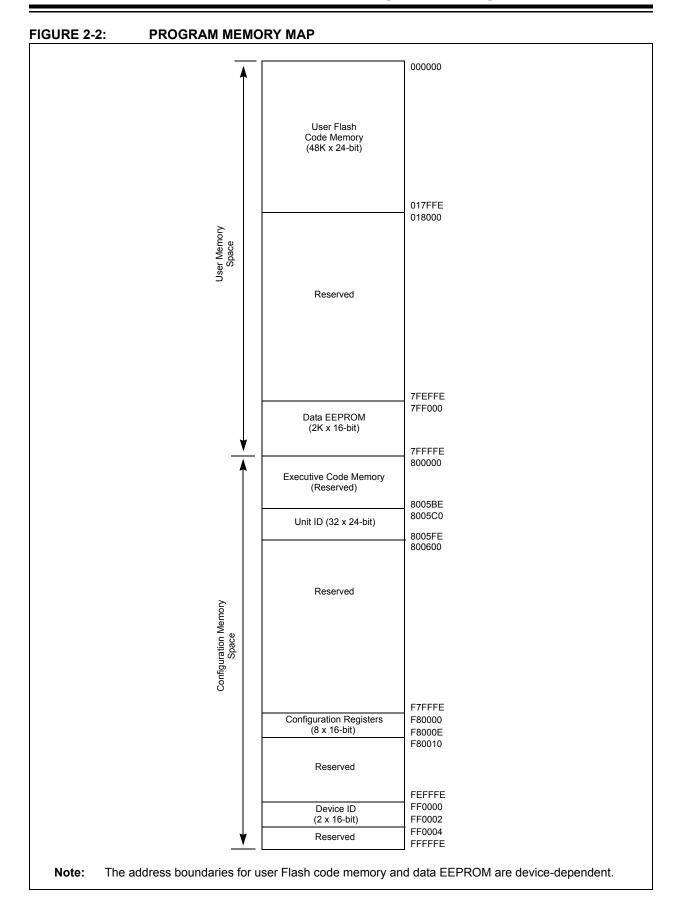
Details

E·XFl

Details	
Product Status	Obsolete
Core Processor	dsPIC
Core Size	16-Bit
Speed	20 MIPS
Connectivity	CANbus, I²C, SPI, UART/USART
Peripherals	AC'97, Brown-out Detect/Reset, I ² S, LVD, POR, PWM, WDT
Number of I/O	68
Program Memory Size	66KB (22K x 24)
Program Memory Type	FLASH
EEPROM Size	1K x 8
RAM Size	4K x 8
Voltage - Supply (Vcc/Vdd)	2.5V ~ 5.5V
Data Converters	A/D 16x12b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	80-TQFP
Supplier Device Package	80-TQFP (12x12)
Purchase URL	https://www.e-xfl.com/product-detail/microchip-technology/dspic30f5013t-20i-ptg

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5.5 Code Memory Programming

5.5.1 OVERVIEW

The Flash code memory array consists of 512 rows of thirty-two, 24-bit instructions. Each panel stores 16K instruction words, and each dsPIC30F device has either 1, 2 or 3 memory panels (see Table 5-2).

Device	Code Size (24-bit Words)	Number of Rows	Number of Panels
dsPIC30F2010	4K	128	1
dsPIC30F2011	4K	128	1
dsPIC30F2012	4K	128	1
dsPIC30F3010	8K	256	1
dsPIC30F3011	8K	256	1
dsPIC30F3012	8K	256	1
dsPIC30F3013	8K	256	1
dsPIC30F3014	8K	256	1
dsPIC30F4011	16K	512	1
dsPIC30F4012	16K	512	1
dsPIC30F4013	16K	512	1
dsPIC30F5011	22K	704	2
dsPIC30F5013	22K	704	2
dsPIC30F5015	22K	704	2
dsPIC30F5016	22K	704	2
dsPIC30F6010	48K	1536	3
dsPIC30F6010A	48K	1536	3
dsPIC30F6011	44K	1408	3
dsPIC30F6011A	44K	1408	3
dsPIC30F6012	48K	1536	3
dsPIC30F6012A	48K	1536	3
dsPIC30F6013	44K	1408	3
dsPIC30F6013A	44K	1408	3
dsPIC30F6014	48K	1536	3
dsPIC30F6014A	48K	1536	3
dsPIC30F6015	48K	1536	3

TABLE 5-2: DEVICE CODE MEMORY SIZE

5.5.2 PROGRAMMING METHODOLOGY

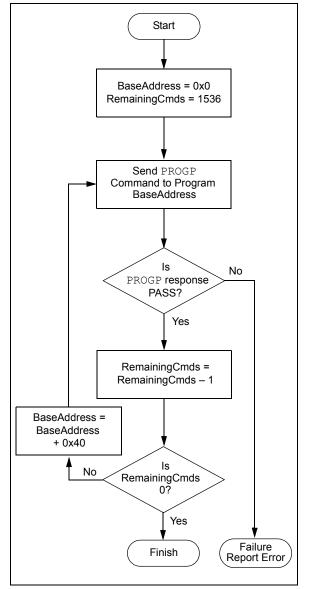
Code memory is programmed with the PROGP command. PROGP programs one row of code memory to the memory address specified in the command. The number of PROGP commands required to program a device depends on the number of rows that must be programmed in the device.

A flowchart for programming of code memory is illustrated in Figure 5-3. In this example, all 48K instruction words of a dsPIC30F6014A device are programmed. First, the number of commands to send (called 'RemainingCmds' in the flowchart) is set to 1536 and the destination address (called 'BaseAddress') is set to '0'. Next, one row in the device is programmed with a PROGP command. Each PROGP command contains data for one row of code memory of the dsPIC30F6014A. After the first command is processed successfully, 'RemainingCmds' is decremented by 1 and compared to 0. Since there are more PROGP commands to send, 'BaseAddress' is incremented by 0x40 to point to the next row of memory.

On the second PROGP command, the second row of each memory panel is programmed. This process is repeated until the entire device is programmed. No special handling must be performed when a panel boundary is crossed.



FLOWCHART FOR PROGRAMMING dsPIC30F6014A CODE MEMORY



Bit Field	Register	Description
EBS	FBS	Boot Segment Data EEPROM Code Protection (only present in dsPIC30F5011/ 5013/6010A/6011A/6012A/6013A/6014A/6015) 1 = No Data EEPROM is reserved for Boot Segment 0 = 128 bytes of Data EEPROM are reserved for Boot Segment in dsPIC30F5011/ 5013, and 256 bytes in dsPIC30F6010A/6011A/6012A/6013A/6014A/6015
BSS<2:0>	FBS	Boot Segment Program Memory Code Protection (only present in dsPIC30F5011/5013/6010A/6011A/6012A/6013A/6014A/6015) 111 = No Boot Segment 110 = Standard security; Small-sized Boot Program Flash [Boot Segment starts after BS and ends at 0x0003FF] 101 = Standard security; Medium-sized Boot Program Flash [Boot Segment starts after BS and ends at 0x0007FF] 100 = Standard security; Large-sized Boot Program Flash [Boot Segment starts after BS and ends at 0x0007FF] 100 = Standard security; Large-sized Boot Program Flash [Boot Segment starts after BS and ends at 0x001FF] 011 = No Boot Segment 010 = High security; Small-sized Boot Program Flash [Boot Segment starts after BS and ends at 0x0003FF] 011 = High security; Medium-sized Boot Program Flash [Boot Segment starts after BS and ends at 0x0003FF] 001 = High security; Medium-sized Boot Program Flash [Boot Segment starts after BS and ends at 0x0007FF] 001 = High security; Large-sized Boot Program Flash [Boot Segment starts after BS and ends at 0x0007FF] 000 = High security; Large-sized Boot Program Flash [Boot Segment starts after BS and ends at 0x0007FF] 000 = High security; Large-sized Boot Program Flash [Boot Segment starts after BS and ends at 0x0007FF]
BWRP	FBS	Boot Segment Program Memory Write Protection (only present in dsPIC30F5011/5013/6010A/6011A/6012A/6013A/6014A/6015) 1 = Boot Segment program memory is not write-protected 0 = Boot Segment program memory is write-protected
RSS<1:0>	FSS	Secure Segment Data RAM Code Protection (only present in dsPIC30F5011/ 5013/6010A/6011A/6012A/6013A/6014A/6015) 11 = No Data RAM is reserved for Secure Segment 10 = Small-sized Secure RAM [(256 - N) bytes of RAM are reserved for Secure Segment] 01 = Medium-sized Secure RAM [(768 - N) bytes of RAM are reserved for Secure Segment in dsPIC30F5011/ 5013, and (2048 - N) bytes in dsPIC30F6010A/6011A/6012A/6013A/6014A/ 6015] 00 = Large-sized Secure RAM [(1024 - N) bytes of RAM are reserved for Secure Segment in dsPIC30F5011/ 5013, and (4096 - N) bytes in dsPIC30F6010A/6011A/6012A/6013A/6014A/ 6015] where N = Number of bytes of RAM reserved for Boot Sector.
ESS<1:0>	FSS	 Secure Segment Data EEPROM Code Protection (only present in dsPIC30F5011/5013/6010A/6011A/6012A/6013A/6014A/6015) 11 = No Data EEPROM is reserved for Secure Segment 10 = Small-sized Secure Data EEPROM [(128 – N) bytes of Data EEPROM are reserved for Secure Segment in dsPIC30F5011/5013, and (256 – N) bytes in dsPIC30F6010A/6011A/6012A/6013A/6014A/6015] 01 = Medium-sized Secure Data EEPROM [(256 – N) bytes of Data EEPROM are reserved for Secure Segment in dsPIC30F5011/5013, and (512 – N) bytes in dsPIC30F6010A/6011A/6012A/6013A/6014A/6015] 01 = Large-sized Secure Data EEPROM [(512 – N) bytes of Data EEPROM [(512 – N) bytes of Data EEPROM are reserved for Secure Segment in dsPIC30F5011/5013, (1024 – N) bytes in dsPIC30F6011A/6013A, and (2048 – N) bytes in dsPIC30F6010A/6012A/6014A/6015]

TABLE 5-7: CONFIGURATION BITS DESCRIPTION (CONTINUED)

TABLE 5-8: dsPIC30F CONFIGURATION REGISTERS (FOR dsPIC30F2010, dsPIC30F4011/4012 AND dsPIC30F6010/ 6011/6012/6013/ 6014)

Address	Name	Bit 15	Bit 14	Bit 13	Bit 12	Bit 11	Bit 10	Bit 9	Bit 8	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
0xF80000	FOSC	FCKSN	1<1:0>	—	_	-	_	FOS	<1:0>	—	_	—	—	FPR<3:0>			
0xF80002	FWDT	FWDTEN	_	_	_	_	_	_	_	_	_	FWPS	A<1:0>		FWPSB<3:0>		
0xF80004	FBORPOR	MCLREN	_	_	_	_	PWMPIN ⁽¹⁾	HPOL ⁽¹⁾	LPOL ⁽¹⁾	BOREN	_	BORV	/<1:0>	_	_	FPWR	T<1:0>
0xF80006	FBS	—	_	Reser	ved ⁽²⁾	_	_	_	Reserved ⁽²⁾	_	_	_	_		Reserv	/ed ⁽²⁾	
0xF80008	FSS	—	_	Reser	ved ⁽²⁾	-	_	Rese	rved ⁽²⁾	—	_	_	_		Reserved ⁽²⁾		
0xF8000A	FGS	—	_	_	_	-	_	—	—	_	_	_	_	_	Reserved ⁽²⁾	GCP	GWRP
0xF8000C	FICD	BKBUG	COE	_	_	—	—	—	—	_	—	_	_	_	_	ICS<	:1:0>

 On the 6011, 6012, 6013 and 6014, these bits are reserved (read as '1' and must be programmed as '1').
 Reserved bits read as '1' and must be programmed as '1'. Note

TABLE 5-9: dsPIC30F CONFIGURATION REGISTERS (FOR dsPIC30F5011/5013)

Address	Name	Bit 15	Bit 14	Bit 13	Bit 12	Bit 11	Bit 10	Bit 9	Bit 8	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
0xF80000	FOSC	FCKSM	1<1:0>	—	—	-	_	FOS	i<1:0>	—	_	—	—		FPR<	3:0>	
0xF80002	FWDT	FWDTEN	_	_	_	—	_	_	_	_	_	FWPS	A<1:0>		FWPSE	3<3:0>	
0xF80004	FBORPOR	MCLREN	_	_	_	—	F	Reserved ⁽¹⁾		BOREN	_	BOR\	/<1:0>	—	_	FPWR	T<1:0>
0xF80006	FBS	_	_	RBS	<1:0>	_	_	—	EBS	—	_	—	_		BSS<2:0>		BWRP
0xF80008	FSS	_	_	RSS	<1:0>	_	—	ESS	<1:0>	_	_	_	_		SSS<2:0>		SWRP
0xF8000A	FGS	_		—	_	—	_	—	_	_	_	—	—	_	GSS<	1:0>	GWRP
0xF8000C	FICD	BKBUG	COE	_	_	—	_	_	_	_	_	_	_	—	_	ICS<	<1:0>

Note 1: Reserved bits read as '1' and must be programmed as '1'.

TABLE 5-10: dsPIC30F CONFIGURATION REGISTERS (FOR dsPIC30F2011/2012, dsPIC30F3010/3011/3012/3013/3014, dsPIC30F4013 AND dsPIC30F5015/5016)

Address	Name	Bit 15	Bit 14	Bit 13	Bit 12	Bit 11	Bit 10	Bit 9	Bit 8	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
0xF80000	FOSC	FCKSN	1<1:0>	—	—			FOS<2:0>		—	_	_			FPR<4:0>		
0xF80002	FWDT	FWDTEN	_	_	_	_	_	_	_	_	_	FWPS	A<1:0>		FWPSB<3:0>		
0xF80004	FBORPOR	MCLREN	_	_	_	_	PWMPIN ⁽¹⁾	HPOL ⁽¹⁾	LPOL ⁽¹⁾	BOREN	_	BORV	/<1:0>	_	_	FPWR	T<1:0>
0xF80006	FBS	_	_	Reser	ved ⁽²⁾	_	_	_	Reserved ⁽²⁾	_	_	_	_		Reserv	/ed ⁽²⁾	
0xF80008	FSS	_	_	Reser	ved ⁽²⁾	_	_	Rese	erved ⁽²⁾	_	_	_	_		Reserv	/ed ⁽²⁾	
0xF8000A	FGS	—	_	_	_	-	_	_	_	_	—	_	—	_	Reserved ⁽³⁾	GCP	GWRP
0xF8000C	FICD	BKBUG	COE	—	—	_	—	_	—	—	_	_	_	_	—	ICS<	<1:0>

1: On the 2011, 2012, 3012, 3013, 3014 and 4013, these bits are reserved (read as '1' and must be programmed as '1'). 2: Reserved bits read as '1' and must be programmed as '1'. Note

3: The FGS<2> bit is a read-only copy of the GCP bit (FGS<1>).

TABLE 5-11: dsPIC30F CONFIGURATION REGISTERS (FOR dsPIC30F6010A/6011A/6012A/6013A/6014A AND dsPIC30F6015)

Address	Name	Bit 15	Bit 14	Bit 13	Bit 12	Bit 11	Bit 10	Bit 9	Bit 8	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
0xF80000	FOSC	FCKSN	l<1:0>	—	-			FOS<2:0>		_	_	_			FPR<4:0>		
0xF80002	FWDT	FWDTEN	—	_	_	_	_	_	_	_	_	FWPS	A<1:0>		FWPSE	3<3:0>	
0xF80004	FBORPOR	MCLREN	_	_	_	_	PWMPIN ⁽¹⁾	HPOL ⁽¹⁾	LPOL ⁽¹⁾	BOREN	_	BORV	/<1:0>	_	_	FPWR	T<1:0>
0xF80006	FBS	—	_	RBS	<1:0>	_	—	_	EBS	—	_	_	—		BSS<2:0>		BWRP
0xF80008	FSS	_	_	RSS	<1:0>	-	_	ESS	s<1:0>	—	_	—	_		SSS<2:0>		SWRP
0xF8000A	FGS	_	_	_	_	_	_	_	_	—	_	_	—	_	GSS<	:1:0>	GWRP
0xF8000C	FICD	BKBUG	COE	—	_		—			_	_	—	_	_	_	ICS<	<1:0>

Note 1: On the 6011A, 6012A, 6013A and 6014A, these bits are reserved (read as '1' and must be programmed as '1').

5.7.2 PROGRAMMING METHODOLOGY

System operation Configuration bits are inherently different than all other memory cells. Unlike code memory, data EEPROM and code-protect Configuration bits, the system operation bits cannot be erased. If the chip is erased with the ERASEB command, the system-operation bits retain their previous value. Consequently, you should make no assumption about the value of the system operation bits. They should always be programmed to their desired setting.

Configuration bits are programmed as a single word at a time using the PROGC command. The PROGC command specifies the configuration data and Configuration register address. When Configuration bits are programmed, any unimplemented bits must be programmed with a '0', and any reserved bits must be programmed with a '1'.

Four PROGC commands are required to program all the Configuration bits. Figure 5-5 illustrates the flowchart of Configuration bit programming.

Note: If the General Code Segment Code Protect (GCP) bit is programmed to '0', code memory is code-protected and cannot be read. Code memory must be verified before enabling read protection. See Section 5.7.4 "Code-Protect Configuration Bits" for more information about code-protect Configuration bits.

5.7.3 PROGRAMMING VERIFICATION

Once the Configuration bits are programmed, the contents of memory should be verified to ensure that the programming was successful. Verification requires the Configuration bits to be read back and compared against the copy held in the programmer's buffer. The READD command reads back the programmed Configuration bits and verifies whether the programming was successful.

Any unimplemented Configuration bits are read-only and read as '0'.

5.7.4 CODE-PROTECT CONFIGURATION BITS

The FBS, FSS and FGS Configuration registers are special Configuration registers that control the size and level of code protection for the Boot Segment, Secure Segment and General Segment, respectively. For each segment, two main forms of code protection are provided. One form prevents code memory from being written (write protection), while the other prevents code memory from being read (read protection).

The BWRP, SWRP and GWRP bits control write protection; and BSS<2:0>, SSS<2:0> and GSS<1:0> bits control read protection. The Chip Erase ERASEB command sets all the code protection bits to '1', which allows the device to be programmed.

When write protection is enabled, any programming operation to code memory will fail. When read protection is enabled, any read from code memory will cause a '0x0' to be read, regardless of the actual contents of code memory. Since the programming executive always verifies what it programs, attempting to program code memory with read protection enabled will also result in failure.

It is imperative that all code protection bits are '1' while the device is being programmed and verified. Only after the device is programmed and verified should any of the above bits be programmed to '0' (see Section 5.7 "Configuration Bits Programming").

In addition to code memory protection, parts of data EEPROM and/or data RAM can be configured to be accessible only by code resident in the Boot Segment and/or Secure Segment. The sizes of these "reserved" sections are user-configurable, using the EBS, RBS<1:0>, ESS<1:0> and RSS<1:0> bits.

- Note 1: All bits in the FBS, FSS and FGS Configuration registers can only be programmed to a value of '0'. ERASEB is the only way to reprogram code-protect bits from ON ('0') to OFF ('1').
 - 2: If any of the code-protect bits in FBS, FSS, or FGS are clear, the entire device must be erased before it can be reprogrammed.

6.6 Configuration Information in the Hexadecimal File

To allow portability of code, the programmer must read the Configuration register locations from the hexadecimal file. If configuration information is not present in the hexadecimal file, a simple warning message should be issued by the programmer. Similarly, while saving a hexadecimal file, all configuration information must be included. An option to not include the configuration information can be provided.

Microchip Technology Inc. feels strongly that this feature is important for the benefit of the end customer.

6.7 Unit ID

The dsPIC30F devices contain 32 instructions of Unit ID. These are located at addresses 0x8005C0 through 0x8005FF. The Unit ID can be used for storing product information such as serial numbers, system manufacturing dates, manufacturing lot numbers and other such application-specific information.

A Bulk Erase does not erase the Unit ID locations. Instead, erase all executive memory using steps 1-4 as shown in Table 12-1, and program the Unit ID along with the programming executive. Alternately, use a Row Erase to erase the row containing the Unit ID locations.

6.8 Checksum Computation

Checksums for the dsPIC30F are 16 bits in size. The checksum is to total sum of the following:

- · Contents of code memory locations
- · Contents of Configuration registers

Table A-1 describes how to calculate the checksum for each device. All memory locations are summed one byte at a time, using only their native data size. More specifically, Configuration and device ID registers are summed by adding the lower two bytes of these locations (the upper byte is ignored), while code memory is summed by adding all three bytes of code memory.

Note: The checksum calculation differs depending on the code-protect setting. Table A-1 describes how to compute the checksum for an unprotected device and a read-protected device. Regardless of the code-protect setting, the Configuration registers can always be read.

7.0 PROGRAMMER – PROGRAMMING EXECUTIVE COMMUNICATION

7.1 Communication Overview

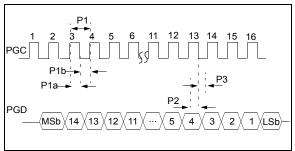
The programmer and programming executive have a master-slave relationship, where the programmer is the master programming device and the programming executive is the slave.

All communication is initiated by the programmer in the form of a command. Only one command at a time can be sent to the programming executive. In turn, the programming executive only sends one response to the programmer after receiving and processing a command. The programming executive command set is described in Section 8.0 "Programming Executive Commands". The response set is described in Section 9.0 "Programming Executive Responses".

7.2 Communication Interface and Protocol

The Enhanced ICSP interface is a 2-wire SPI interface implemented using the PGC and PGD pins. The PGC pin is used as a clock input pin, and the clock source must be provided by the programmer. The PGD pin is used for sending command data to, and receiving response data from, the programming executive. All serial data is transmitted on the falling edge of PGC and latched on the rising edge of PGC. All data transmissions are sent Most Significant bit (MSb) first, using 16-bit mode (see Figure 7-1).

FIGURE 7-1: PROGRAMMING EXECUTIVE SERIAL TIMING



Since a 2-wire SPI interface is used, and data transmissions are bidirectional, a simple protocol is used to control the direction of PGD. When the programmer completes a command transmission, it releases the PGD line and allows the programming executive to drive this line high. The programming executive keeps the PGD line high to indicate that it is processing the command.

After the programming executive has processed the command, it brings PGD low for 15 μ sec to indicate to the programmer that the response is available to be

clocked out. The programmer can begin to clock out the response 20 μ sec after PGD is brought low, and it must provide the necessary amount of clock pulses to receive the entire response from the programming executive.

Once the entire response is clocked out, the programmer should terminate the clock on PGC until it is time to send another command to the programming executive. This protocol is illustrated in Figure 7-2.

7.3 SPI Rate

In Enhanced ICSP mode, the dsPIC30F operates from the fast internal RC oscillator, which has a nominal frequency of 7.37 MHz. This oscillator frequency yields an effective system clock frequency of 1.84 MHz. Since the SPI module operates in Slave mode, the programmer must limit the SPI clock rate to a frequency no greater than 1 MHz.

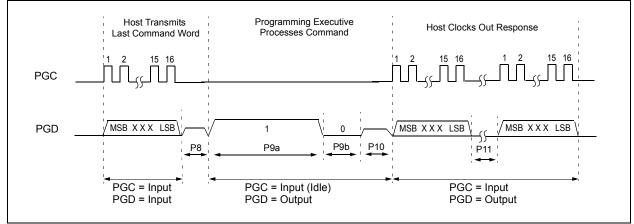
Note:	If the programmer provides the SPI with a clock faster than 1 MHz, the behavior of
	the programming executive will be unpredictable.

7.4 Time Outs

The programming executive uses no Watchdog Timer or time out for transmitting responses to the programmer. If the programmer does not follow the flow control mechanism using PGC, as described in Section 7.2 "Communication Interface and Protocol", it is possible that the programming executive will behave unexpectedly while trying to send a response to the programmer. Since the programming executive has no time out, it is imperative that the programmer correctly follow the described communication protocol.

As a safety measure, the programmer should use the command time outs identified in Table 8-1. If the command time out expires, the programmer should reset the programming executive and start programming the device again.

FIGURE 7-2: PROGRAMMING EXECUTIVE – PROGRAMMER COMMUNICATION PROTOCOL



Opcode	Mnemonic	Length (16-bit words)	Time Out	Description
0x0	SCHECK	1	1 ms	Sanity check.
0x1	READD	4	1 ms/row	Read N 16-bit words of data EEPROM, Configuration registers or device ID starting from specified address.
0x2	READP	4	1 ms/row	Read N 24-bit instruction words of code memory starting from specified address.
0x3	Reserved	N/A	N/A	This command is reserved. It will return a NACK.
0x4	PROGD ⁽²⁾	19	5 ms	Program one row of data EEPROM at the specified address, then verify.
0x5	PROGP(1)	51	5 ms	Program one row of code memory at the specified address, then verify.
0x6	PROGC	4	5 ms	Write byte or 16-bit word to specified Configuration register.
0x7	ERASEB	2	5 ms	Bulk Erase (entire code memory or data EEPROM), or erase by segment.
0x8	ERASED ⁽²⁾	3	5 ms/row	Erase rows of data EEPROM from specified address.
0x9	ERASEP(1)	3	5 ms/row	Erase rows of code memory from specified address.
0xA	QBLANK	3	300 ms	Query if the code memory and data EEPROM are blank.
0xB	QVER	1	1 ms	Query the programming executive software version.

TABLE 8-1: PROGRAMMING EXECUTIVE COMMAND SET

Note 1: One row of code memory consists of (32) 24-bit words. Refer to Table 5-2 for device-specific information.
2: One row of data EEPROM consists of (16) 16-bit words. Refer to Table 5-3 for device-specific information.

8.5 Command Descriptions

All commands that are supported by the programming executive are described in Section 8.5.1 "SCHECK Command" through Section 8.5.11 "QVER Command".

8.5.1 SCHECK COMMAND

15	12	11 0)
	Opcode	Length	

Field	Description
Opcode	0x0
Length	0x1

The SCHECK command instructs the programming executive to do nothing, but generate a response. This command is used as a "sanity check" to verify that the programming executive is operational.

Expected Response (2 words):

0x1000 0x0002

Note: This instruction is not required for programming, but is provided for development purposes only.

8.5.2 READD COMMAND

15	12	11	8	7	0
Орс	ode			Length	
Reser	ved0			Ν	
	Reser	ved1		Addr_MSB	
			Addr_	LS	

Field	Description
Opcode	0x1
Length	0x4
Reserved0	0x0
N	Number of 16-bit words to read (max of 2048)
Reserved1	0x0
Addr_MSB	MSB of 24-bit source address
Addr_LS	LS 16 bits of 24-bit source address

The READD command instructs the programming executive to read N 16-bit words of memory starting from the 24-bit address specified by Addr_MSB and Addr_LS. This command can only be used to read 16-bit data. It can be used to read data EEPROM, Configuration registers and the device ID.

Expected Response (2+N words):

0x1100 N + 2 Data word 1

Data word N

Note: Reading unimplemented memory will cause the programming executive to reset.

dsPIC30F Flash Programming Specification

8.5.3 READP COMMAND

15	12	11	8	7	0
Opcode Length					
			Ν		
	Rese	rved		Addr_MSB	
	Addr_LS				

Field	Description
Opcode	0x2
Length	0x4
Ν	Number of 24-bit instructions to read (max of 32768)
Reserved	0x0
Addr_MSB	MSB of 24-bit source address
Addr_LS	LS 16 bits of 24-bit source address

The READP command instructs the programming executive to read N 24-bit words of code memory starting from the 24-bit address specified by Addr_MSB and Addr_LS. This command can only be used to read 24-bit data. All data returned in response to this command uses the packed data format described in Section 8.3 "Packed Data Format".

Expected Response (2 + 3 * N/2 words for N even): 0x1200

2 + 3 * N/2 Least significant program memory word 1

Least significant data word N

Expected Response (4 + 3 * (N - 1)/2 words for N odd):

0x12004 + 3 * (N - 1)/2 Least significant program memory word 1

MSB of program memory word N (zero padded)

Note: Reading unimplemented memory will cause the programming executive to reset.

8.5.4 PROGD COMMAND

15	12	11	11 8 7 0			
Орс	ode			L	ength	
	Rese	rved			Addr_MSB	
Addr_LS						
	 D_1					
	D_2					
	D_16					

Field	Description
Opcode	0x4
Length	0x13
Reserved	0x0
Addr_MSB	MSB of 24-bit destination address
Addr_LS	LS 16 bits of 24-bit destination address
D_1	16-bit data word 1
D_2	16-bit data word 2
	16-bit data words 3 through 15
D_16	16-bit data word 16

The PROGD command instructs the programming executive to program one row of data EEPROM. The data to be programmed is specified by the 16 data words (D_1, D_2,..., D_16) and is programmed to the destination address specified by Addr_MSB and Addr_LSB. The destination address should be a multiple of 0x20.

Once the row of data EEPROM has been programmed, the programming executive verifies the programmed data against the data in the command.

Expected Response (2 words):

0x1400 0x0002

Note: Refer to Table 5-3 for data EEPROM size information.

8.5.5 PROGP COMMAND

15	12	11	8	7		0
Орс	ode			L	ength	
	Rese	rved			Addr_MSB	
	Addr_LS					
	D_1					
			D_2	2		
	D_N					

Field	Description
Opcode	0x5
Length	0x33
Reserved	0x0
Addr_MSB	MSB of 24-bit destination address
Addr_LS	LS 16 bits of 24-bit destination address
D_1	16-bit data word 1
D_2	16-bit data word 2
	16-bit data word 3 through 47
D_48	16-bit data word 48

The PROGP command instructs the programming executive to program one row of code memory (32 instruction words) to the specified memory address. Programming begins with the row address specified in the command. The destination address should be a multiple of 0x40.

The data to program to memory, located in command words D_1 through D_48, must be arranged using the packed instruction word format shown in Figure 8-2.

After all data has been programmed to code memory, the programming executive verifies the programmed data against the data in the command.

Expected Response (2 words): 0x1500 0x0002

Note: Refer to Table 5-2 for code memory size information.

8.5.6 PROGC COMMAND

15	12	11	8	7		0
Орс	ode			L	ength	
Reserved				Addr_MSB		
			Addr_	LS		
Data						

Field	Description
Opcode	0x6
Length	0x4
Reserved	0x0
Addr_MSB	MSB of 24-bit destination address
Addr_LS	LS 16 bits of 24-bit destination address
Data	Data to program

The PROGC command programs data to the specified Configuration register and verifies the programming. Configuration registers are 16 bits wide, and this command allows one Configuration register to be programmed.

Expected Response (2 words): 0x1600 0x0002

Note: This command can only be used for programming Configuration registers.

11.4 Flash Memory Programming in ICSP Mode

Programming in ICSP mode is described in Section 11.4.1 "Programming Operations" through Section 11.4.3 "Starting and Stopping a Programming Cycle". Step-by-step procedures are described in Section 11.5 "Erasing Program Memory in Normal-Voltage Systems" through Section 11.13 "Reading the Application ID Word". All programming operations must use serial execution, as described in Section 11.2 "ICSP Operation".

11.4.1 PROGRAMMING OPERATIONS

Flash memory write and erase operations are controlled by the NVMCON register. Programming is performed by setting NVMCON to select the type of erase operation (Table 11-2) or write operation (Table 11-3), writing a key sequence to enable the programming and initiating the programming by setting the WR control bit, NVMCON<15>.

In ICSP mode, all programming operations are externally timed. An external 2 ms delay must be used between setting the WR control bit and clearing the WR control bit to complete the programming operation.

TABLE 11-2: NVMCON ERASE OPERATIONS

NVMCON Value	Erase Operation
0x407F	Erase all code memory, data memory (does not erase UNIT ID).
0x4075	Erase 1 row (16 words) of data EEPROM.
0x4074	Erase 1 word of data EEPROM.
0x4072	Erase all executive memory.
0x4071	Erase 1 row (32 instruction words) from 1 panel of code memory.
0x406E	Erase Boot Secure and General Segments, then erase FBS, FSS and FGS configuration registers.
0x4066	Erase all Data EEPROM allocated to Boot Segment.
0x405E	Erase Secure and General Segments, then erase FSS and FGS configuration registers.
0x4056	Erase all Data EEPROM allocated to Secure Segment.
0x404E	Erase General Segment, then erase FGS configuration register.
0x4046	Erase all Data EEPROM allocated to General Segment.

TABLE 11-3: NVMCON WRITE OPERATIONS

NVMCON Value	Write Operation
0x4008	Write 1 word to configuration
	memory.
0x4005	Write 1 row (16 words) to data memory.
0x4004	Write 1 word to data memory.
0x4001	Write 1 row (32 instruction words) into 1 panel of program memory.

11.4.2 UNLOCKING NVMCON FOR PROGRAMMING

Writes to the WR bit (NVMCON<15>) are locked to prevent accidental programming from taking place. Writing a key sequence to the NVMKEY register unlocks the WR bit and allows it to be written to. The unlock sequence is performed as follows:

MOV	#0x55, W8
MOV	W8, NVMKEY
MOV	#OxAA, W9
MOV	W9, NVMKEY
Note:	Any working register, or working register pair, can be used to write the unlock sequence.

11.4.3 STARTING AND STOPPING A PROGRAMMING CYCLE

Once the unlock key sequence has been written to the NVMKEY register, the WR bit (NVMCON<15>) is used to start and stop an erase or write cycle. Setting the WR bit initiates the programming cycle. Clearing the WR bit terminates the programming cycle.

All erase and write cycles must be externally timed. An external delay must be used between setting and clearing the WR bit. Starting and stopping a programming cycle is performed as follows:

BSET	NVMCON,	#WR
<wait< td=""><td>2 ms></td><td></td></wait<>	2 ms>	
BCLR	NVMCON,	#WR

11.5 Erasing Program Memory in Normal-Voltage Systems

The procedure for erasing program memory (all code memory, data memory, executive memory and codeprotect bits) consists of setting NVMCON to 0x407F, unlocking NVMCON for erasing and then executing the programming cycle. This method of bulk erasing program memory only works for systems where VDD is between 4.5 volts and 5.5 volts. The method for erasing program memory for systems with a lower VDD (3.0 volts-4.5 volts) is described in Section 6.1 "Erasing Memory". Table 11-4 shows the ICSP programming process for bulk-erasing program memory. This process includes the ICSP command code, which must be transmitted (for each instruction) to the Least Significant bit first using the PGC and PGD pins (see Figure 11-2).

If an individual Segment Erase operation is required, the NVMCON value must be replaced by the value for the corresponding Segment Erase operation.

Note:	Program memory must be erased before
	writing any data to program memory.

TABLE 11-4:SERIAL INSTRUCTION EXECUTION FOR BULK ERASING PROGRAM MEMORY
(ONLY IN NORMAL-VOLTAGE SYSTEMS)

Command (Binary)	Data (Hexadecimal)	Description
Step 1: Exit t	ne Reset vector.	<u>+</u>
0000	040100	GOTO 0x100
0000	040100	GOTO 0x100
0000	000000	NOP
Step 2: Set N	VMCON to program	the FBS Configuration register. ⁽¹⁾
0000	24008A	MOV #0x4008, W10
0000	883B0A	MOV W10, NVMCON
Step 3: Initial	ize the TBLPAG and	write pointer (W7) for TBLWT instruction for Configuration register. ⁽¹⁾
0000	200F80	MOV #0xF8, W0
0000	880190	MOV W0, TBLPAG
0000	200067	MOV #0x6, W7
Step 4: Load	the Configuration Re	egister data to W6. ⁽¹⁾
0000	EB0300	CLR W6
0000	000000	NOP
Step 5: Load	the Configuration Re	egister write latch. Advance W7 to point to next Configuration register. ⁽¹⁾
0000	BB1B86	TBLWTL W6, [W7++]
Step 6: Unloc	k the NVMCON for	programming the Configuration register. ⁽¹⁾
0000	200558	MOV #0x55, W8
0000	200AA9	MOV #0xAA, W9
0000	883B38	MOV W8, NVMKEY
0000	883B39	MOV W9, NVMKEY
Step 7: Initiat	e the programming o	cycle. ⁽¹⁾
0000	A8E761	BSET NVMCON, #WR
0000	000000	NOP
0000	000000	NOP
_	-	Externally time 2 ms
0000	000000	NOP
0000	000000	NOP
0000	A9E761	BCLR NVMCON, #WR
0000	000000	NOP
0000	000000	NOP
Step 8: Repe	at steps 5-7 one time	e to program 0x0000 to RESERVED2 Configuration register. ⁽¹⁾
		e all Program Memory.
00000	2407FA	MOV #0x407F, W10
0000	883B0A	MOV W10, NVMCON

Note 1: Steps 2-8 are only required for the dsPIC30F5011/5013 devices. These steps may be skipped for all other devices in the dsPIC30F family.

TABLE 11-4:SERIAL INSTRUCTION EXECUTION FOR BULK ERASING PROGRAM MEMORY
(ONLY IN NORMAL-VOLTAGE SYSTEMS) (CONTINUED)

Command (Binary)	Data (Hexadecimal)	Description	
0000	200558	MOV #0x55, W8	
0000	883B38	MOV W8, NVMKEY	
0000	200AA9	MOV #0xAA, W9	
0000	883B39	MOV W9, NVMKEY	
Step 11: Initia	Step 11: Initiate the erase cycle.		
0000	A8E761	BSET NVMCON, #WR	
0000	000000	NOP	
0000	000000	NOP	
-	_	Externally time 'P13a' ms (see Section 13.0 "AC/DC Characteristics and Timing Requirements")	
0000	000000	NOP	
0000	000000	NOP	
0000	A9E761	BCLR NVMCON, #WR	
0000	000000	NOP	
0000	000000	NOP	

Note 1: Steps 2-8 are only required for the dsPIC30F5011/5013 devices. These steps may be skipped for all other devices in the dsPIC30F family.

Command (Binary)	Data (Hexadecimal)	Description
	ne read pointer (W6)	and load the (next set of) write latches.
0000	EB0300	CLR W6
0000	000000	NOP
0000	BB0BB6	TBLWTL [W6++], [W7]
0000	000000	NOP
0000	000000	NOP
0000	BBDBB6	TBLWTH.B [W6++], [W7++]
0000	000000	NOP
0000	000000	NOP
0000	BBEBB6	TBLWTH.B [W6++], [++W7]
0000	000000	NOP
0000	000000	NOP
0000	BB1BB6	TBLWTL [W6++], [W7++]
0000	000000	NOP
0000	000000	NOP
0000	BB0BB6	TBLWTL [W6++], [W7]
0000	000000	NOP
0000	000000	NOP
0000	BBDBB6	TBLWTH.B [W6++], [W7++]
0000	000000	NOP
0000	000000	NOP
0000	BBEBB6	TBLWTH.B [W6++], [++W7]
0000	000000	NOP
0000	000000	NOP
0000	BB1BB6	TBLWTL [W6++], [W7++]
0000	000000	NOP
0000	000000	NOP
Step 6: Repe	at steps 4-5 eight tir	nes to load the write latches for 32 instructions.
Step 7: Unloc	ck the NVMCON for	writing.
0000	200558	MOV #0x55, W8
0000	883B38	MOV W8, NVMKEY
0000	200AA9	MOV #0xAA, W9
0000	883B39	MOV W9, NVMKEY
Step 8: Initiat	te the write cycle.	
0000	A8E761	BSET NVMCON, #WR
0000	000000	NOP
0000	000000	NOP
_	_	Externally time 'P12a' ms (see Section 13.0 "AC/DC Characteristics and
		Timing Requirements")
0000	000000	NOP
0000	000000	NOP
0000	A9E761	BCLR NVMCON, #WR
0000	000000	NOP
0000	000000	NOP
	t device internal PC.	
Step 9: Rese		
-	040100	GOTO 0x100
Step 9: Rese	040100 000000	GOTO 0x100 NOP

TABLE 11-8: SERIAL INSTRUCTION EXECUTION FOR WRITING CODE MEMORY (CONTINUED)

11.9 Writing Data EEPROM

The procedure for writing data EEPROM is very similar to the procedure for writing code memory, except that fewer words are programmed in each operation. When writing data EEPROM, one row of data EEPROM is programmed at a time. Each row consists of sixteen 16-bit data words. Since fewer words are programmed during each operation, only working registers W0:W3 are used as temporary holding registers for the data to be programmed.

Table 11-9 shows the ICSP programming details for writing data EEPROM. Note that a different NVMCON value is required to write to data EEPROM, and that the TBLPAG register is hard-coded to 0x7F (the upper byte address of all locations of data EEPROM).

	OFRIAL INOTRUCTION EVECUTION FOR WRITING RATA FERROM
TABLE 11-9:	SERIAL INSTRUCTION EXECUTION FOR WRITING DATA EEPROM

Command (Binary)	Data (Hexadecimal)	Description
Step 1: Exit th	e Reset vector.	
0000	040100	GOTO 0x100
0000	040100	GOTO 0x100
0000	000000	NOP
Step 2: Set the	e NVMCON to write	16 data words.
0000	24005A	MOV #0x4005, W10
0000	883B0A	MOV W10, NVMCON
Step 3: Initializ	ze the write pointer	W7) for TBLWT instruction.
0000	2007F0	MOV #0x7F, W0
0000	880190	MOV W0, TBLPAG
0000	2xxxx7	MOV # <destinationaddress15:0>, W7</destinationaddress15:0>
Step 4: Load \	W0:W3 with the nex	4 data words to program.
0000	2xxxx0	MOV # <wordo>, WO</wordo>
0000	2xxxx1	MOV # <word1>, W1</word1>
0000	2xxxx2	MOV # <word2>, W2</word2>
0000	2xxxx3	MOV # <word3>, W3</word3>
Step 5: Set the	e read pointer (W6)	and load the (next set of) write latches.
0000	EB0300	CLR W6
0000	000000	NOP
0000	BB1BB6	TBLWTL [W6++], [W7++]
0000	000000	NOP
0000	000000	NOP
0000	BB1BB6	TBLWTL [W6++], [W7++]
0000	000000	NOP
0000	000000	NOP
0000	BB1BB6	TBLWTL [W6++], [W7++]
0000	000000	NOP
0000	000000	NOP
0000	BB1BB6	TBLWTL [W6++], [W7++]
0000	000000	NOP
0000	000000	NOP
Step 6: Repea	at steps 4-5 four time	es to load the write latches for 16 data words.

Command (Binary)	Data (Hexadecimal)	Description
Step 4: Output	t W0:W5 using th	e VISI register and REGOUT command.
0000	883C20	MOV W0, VISI
0000	000000	NOP
0001	<visi></visi>	Clock out contents of VISI register
0000	000000	NOP
0000	883C21	MOV W1, VISI
0000	000000	NOP
0001	<visi></visi>	Clock out contents of VISI register
0000	000000	NOP
0000	883C22	MOV W2, VISI
0000	000000	NOP
0001	<visi></visi>	Clock out contents of VISI register
0000	000000	NOP
0000	883C23	MOV W3, VISI
0000	000000	NOP
0001	<visi></visi>	Clock out contents of VISI register
0000	000000	NOP
0000	883C24	MOV W4, VISI
0000	000000	NOP
0001	<visi></visi>	Clock out contents of VISI register
0000	000000	NOP
0000	883C25	MOV W5, VISI
0000	000000	NOP
0001	<visi></visi>	Clock out contents of VISI register
0000	000000	NOP
Step 5: Reset	the device intern	al PC.
0000	040100	GOTO 0x100
0000	000000	NOP
Step 6: Repea	at steps 3-5 until a	all desired code memory is read.

TABLE 11-10: SERIAL INSTRUCTION EXECUTION FOR READING CODE MEMORY (CONTINUED)

(Binary)	d Data) (Hexadecim	Description
	•	W6) and load the (next four write) latches.
•		
0000 0000	EB0300 000000	CLR W6 NOP
0000		
	BB0BB6 000000	TBLWTL [W6++], [W7]
0000		NOP
0000	000000	NOP TBLWTH.B [W6++], [W7++]
0000	BBDBB6	
0000	000000	NOP
0000	000000 BBEBB6	
0000		TBLWTH.B [W6++], [++W7]
0000	000000	NOP
0000	000000	NOP
0000	BB1BB6	TBLWTL [W6++], [W7++]
0000	000000	NOP
0000	000000	NOP
0000	BB0BB6	TBLWTL [W6++], [W7]
0000	000000	NOP
0000	000000	NOP
0000	BBDBB6	TBLWTH.B [W6++], [W7++]
0000	000000	NOP
0000	000000	NOP
0000	BBEBB6	TBLWTH.B [W6++], [++W7]
0000	000000	NOP
0000	000000	NOP
0000	BB1BB6	TBLWTL [W6++], [W7++]
0000	000000	NOP
0000	000000	NOP
	· · · ·	ht times to load the write latches for the 32 instructions.
Step 10: 0		N for programming.
0000	200558	MOV #0x55, W8
0000	883B38	MOV W8, NVMKEY
0000	200AA9	MOV #0xAA, W9
0000	883B39	MOV W9, NVMKEY
Step 11: In	itiate the programr	ning cycle.
0000	A8E761	BSET NVMCON, #15
0000		NOD
	000000	NOP
0000	000000 000000	NOP
0000 0000		
0000 0000	000000	NOP Externally time 'P12a' ms (see Section 13.0 "AC/DC Characteristics and
0000 0000 -	000000	NOP
0000 0000 - 0000	000000	NOP Externally time 'P12a' ms (see Section 13.0 "AC/DC Characteristics and Timing Requirements")
0000 0000 0000 0000	000000 000000	NOP Externally time 'P12a' ms (see Section 13.0 "AC/DC Characteristics and Timing Requirements") NOP
0000 0000 - 0000 0000 0000	000000 - 000000 000000	NOP Externally time 'P12a' ms (see Section 13.0 "AC/DC Characteristics and Timing Requirements") NOP NOP
0000 0000 	000000 000000 000000 A9E761	NOP Externally time 'P12a' ms (see Section 13.0 "AC/DC Characteristics and Timing Requirements") NOP NOP BCLR NVMCON, #15
0000 0000 0000 0000 0000 0000	000000 000000 000000 A9E761 000000	NOP Externally time 'P12a' ms (see Section 13.0 "AC/DC Characteristics and Timing Requirements") NOP NOP BCLR NVMCON, #15 NOP NOP
0000 0000 0000 0000 0000 0000	000000 000000 000000 A9E761 000000 000000	NOP Externally time 'P12a' ms (see Section 13.0 "AC/DC Characteristics and Timing Requirements") NOP NOP BCLR NVMCON, #15 NOP NOP

TABLE 12-1: PROGRAMMING THE PROGRAMMING EXECUTIVE (CONTINUED)

Command (Binary)	Data (Hexadecimal)	Description	
Step 4: Outpu	t W0:W5 using th	ne VISI register and REGOUT command.	
0000	883C20	MOV W0, VISI	
0000	000000	NOP	
0001	-	Clock out contents of VISI register	
0000	883C21	MOV W1, VISI	
0000	000000	NOP	
0001	-	Clock out contents of VISI register	
0000	883C22	MOV W2, VISI	
0000	000000	NOP	
0001	-	Clock out contents of VISI register	
0000	883C23	MOV W3, VISI	
0000	000000	NOP	
0001	-	Clock out contents of VISI register	
0000	883C24	MOV W4, VISI	
0000	000000	NOP	
0001	-	Clock out contents of VISI register	
0000	883C25	MOV W5, VISI	
0000	000000	NOP	
0001	-	Clock out contents of VISI register	
Step 5: Reset	Step 5: Reset the device internal PC.		
0000	040100	GOTO 0x100	
0000	000000	NOP	
Step 6: Repea	Step 6: Repeat Steps 3-5 until all 736 instruction words of executive memory are read.		

TABLE 12-2: READING EXECUTIVE MEMORY (CONTINUED)